

N-Channel NexFET™ Power MOSFETs

 Check for Samples: [CSD16340Q3](#)

FEATURES

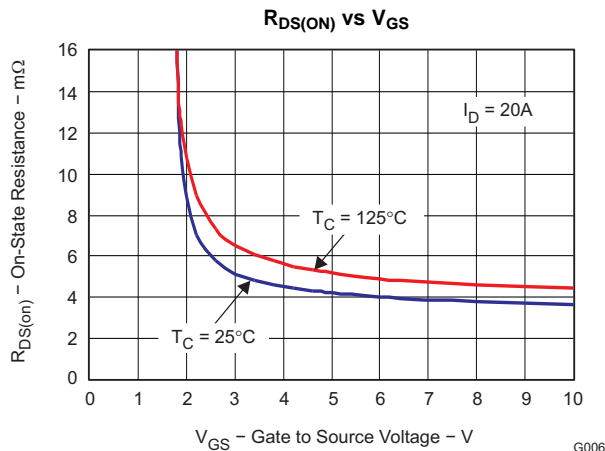
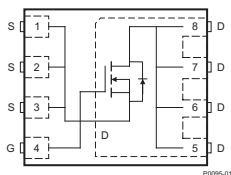
- Optimized for 5V Gate Drive
- Resistance Rated at $V_{GS} = 2.5V$
- Ultra Low Q_g and Q_{gd}
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 3.3mm x 3.3mm Plastic Package

APPLICATIONS

- Point-of-Load Synchronous Buck Converter for Applications in Networking, Telecom and Computing Systems
- Optimized for Control or Synchronous FET Applications

DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion and optimized for 5V gate drive applications.

Figure 1. Top View


PRODUCT SUMMARY

V_{DS}	Drain to Source Voltage	25	V
Q_g	Gate Charge Total (4.5V)	6.5	nC
Q_{gd}	Gate Charge Gate to Drain	1.2	nC
$R_{DS(on)}$	Drain to Source On Resistance	$V_{GS} = 2.5V$	6.1 mΩ
		$V_{GS} = 4.5V$	4.3 mΩ
		$V_{GS} = 8V$	3.8 mΩ
V_{th}	Threshold Voltage	0.85	V

ORDERING INFORMATION

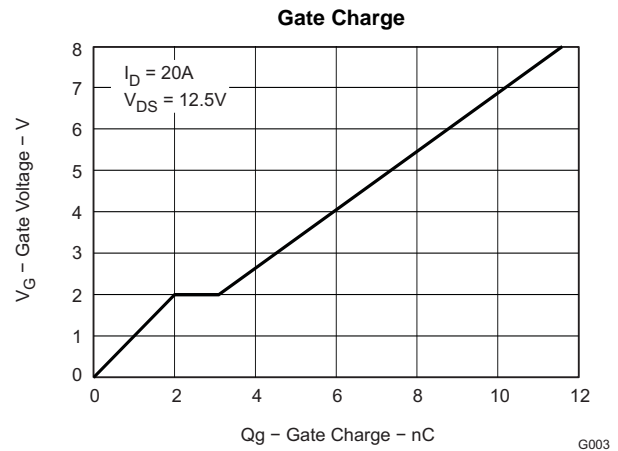
Device	Package	Media	Qty	Ship
CSD16340Q3	SON 3.3 × 3.3 Plastic Package	13-inch reel	2500	Tape and Reel

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ C$ unless otherwise stated		VALUE	UNIT
V_{DS}	Drain to Source Voltage	25	V
V_{GS}	Gate to Source Voltage	+10 / -8	V
I_D	Continuous Drain Current, $T_C = 25^\circ C$	60	A
	Continuous Drain Current ⁽¹⁾	21	A
I_{DM}	Pulsed Drain Current, $T_A = 25^\circ C$ ⁽²⁾	115	A
P_D	Power Dissipation ⁽¹⁾	3	W
T_J, T_{STG}	Operating Junction and Storage Temperature Range	-55 to 150	$^\circ C$
E_{AS}	Avalanche Energy, single pulse $I_D = 40A, L = 0.1mH, R_G = 25\Omega$	80	mJ

(1) Typical $R_{\theta JA} = 39^\circ C/W$ on 1in² Cu (2 oz.) on 0.060" thick FR4 PCB.

(2) Pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$ unless otherwise stated)

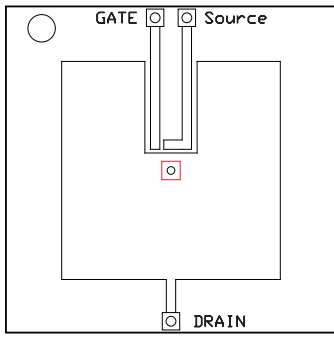
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Characteristics						
BV_{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_{DS} = 250\mu A$	25			V
I_{DSS}	Drain to Source Leakage Current	$V_{GS} = 0V, V_{DS} = 20V$			1	μA
I_{GSS}	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = +10/-8V$			100	nA
$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_{DS} = 250\mu A$	0.6	0.85	1.1	V
$R_{DS(on)}$	Drain to Source On Resistance	$V_{GS} = 2.5V, I_{DS} = 20A$		6.1	7.8	m Ω
		$V_{GS} = 4.5V, I_{DS} = 20A$		4.3	5.5	m Ω
		$V_{GS} = 8V, I_{DS} = 20A$		3.8	4.5	m Ω
g_{fs}	Transconductance	$V_{DS} = 15V, I_{DS} = 20A$		121		S
Dynamic Characteristics						
C_{ISS}	Input Capacitance	$V_{GS} = 0V, V_{DS} = 12.5V, f = 1MHz$		1050	1350	pF
C_{OSS}	Output Capacitance			730	950	pF
C_{RSS}	Reverse Transfer Capacitance			53	69	pF
R_g	Series Gate Resistance			1.5	3	Ω
Q_g	Gate Charge Total (4.5V)	$V_{DS} = 12.5V, I_D = 20A$		6.5	9.2	nC
Q_{gd}	Gate Charge Gate to Drain			1.2		nC
Q_{gs}	Gate Charge Gate to Source			2.1		nC
$Q_{g(th)}$	Gate Charge at V_{th}			1		nC
Q_{OSS}	Output Charge	$V_{DS} = 13V, V_{GS} = 0V$		15		nC
$t_{d(on)}$	Turn On Delay Time	$V_{DS} = 12.5V, V_{GS} = 4.5V, I_D = 20A$ $R_G = 2\Omega$		4.8		ns
t_r	Rise Time			16.1		ns
$t_{d(off)}$	Turn Off Delay Time			13.8		ns
t_f	Fall Time			5.2		ns
Diode Characteristics						
V_{SD}	Diode Forward Voltage	$I_S = 20A, V_{GS} = 0V$		0.8	1	V
Q_{rr}	Reverse Recovery Charge	$V_{DD} = 13V, I_F = 20A, di/dt = 300A/\mu s$		14.5		nC
t_{rr}	Reverse Recovery Time			20		ns

THERMAL INFORMATION

THERMAL METRIC ⁽¹⁾⁽²⁾		CSD16340Q3	UNITS
		Q3 (8 PINS)	
θ_{JA}	Junction-to-ambient thermal resistance	42.0	$^\circ\text{C/W}$
θ_{JcTop}	Junction-to-case (top) thermal resistance	20.6	
θ_{JB}	Junction-to-board thermal resistance	8.8	
ψ_{JT}	Junction-to-top characterization parameter	0.3	
ψ_{JB}	Junction-to-board characterization parameter	8.7	
θ_{JcBot}	Junction-to-case (bottom) thermal resistance	0.1	

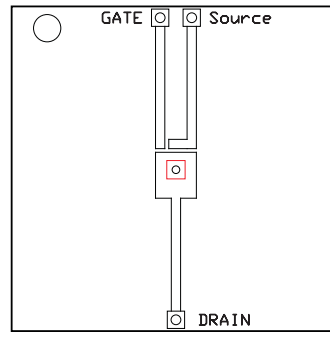
(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

(2) For thermal estimates of this device based on PCB copper area, see the [TI PCB Thermal Calculator](#).



Max $R_{\theta JA} = 58^{\circ}\text{C/W}$
when mounted on 1
 inch^2 of 2 oz. Cu.

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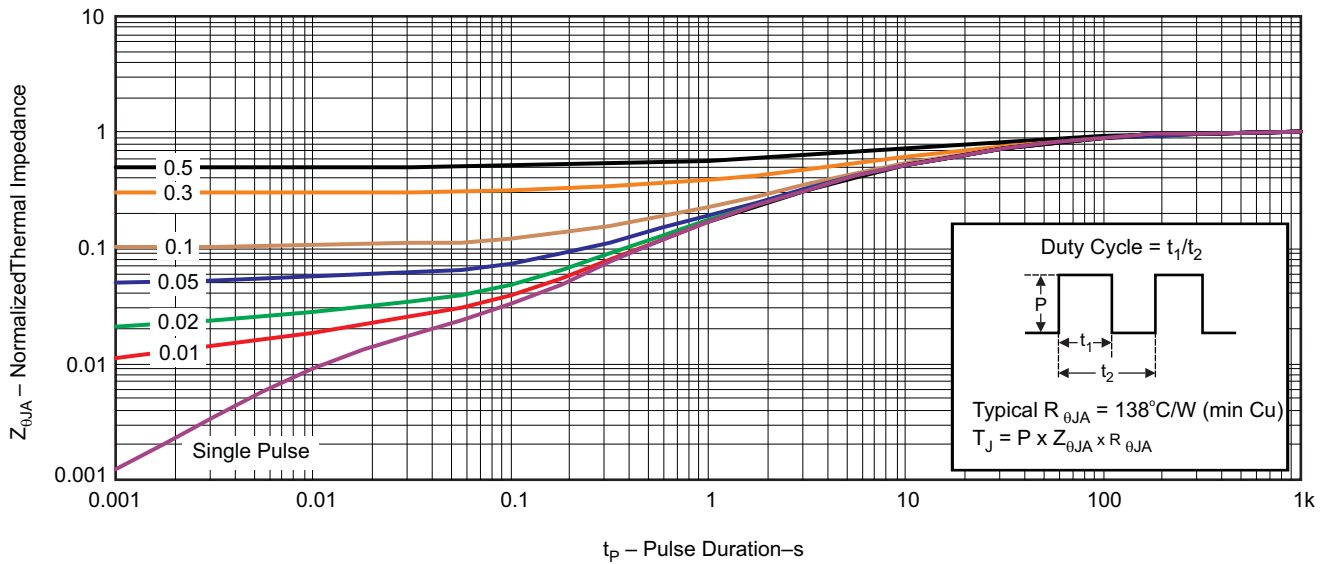


Max $R_{\theta JA} = 162^{\circ}\text{C/W}$
when mounted on
minimum pad area of 2
oz. Cu.

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TYPICAL MOSFET CHARACTERISTICS

($T_A = 25^{\circ}\text{C}$ unless otherwise stated)



G012

Figure 2. Transient Thermal Impedance

TYPICAL MOSFET CHARACTERISTICS (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

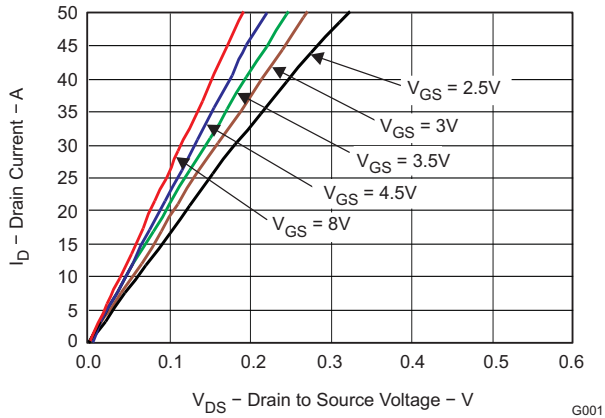


Figure 3. Saturation Characteristics

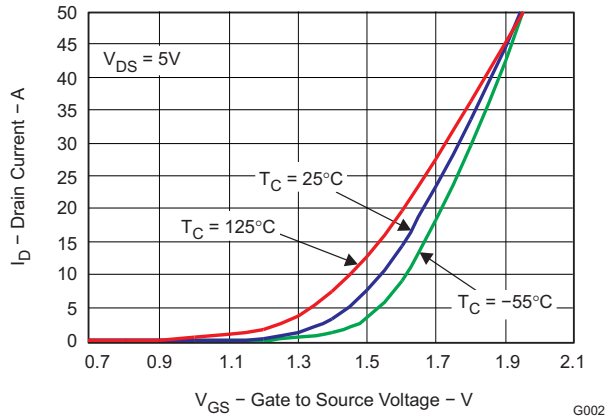


Figure 4. Transfer Characteristics

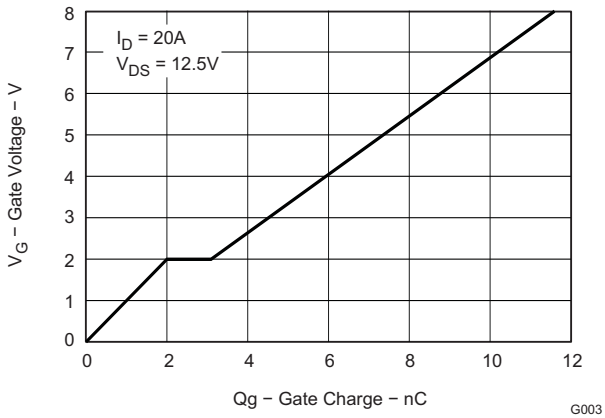


Figure 5. Gate Charge

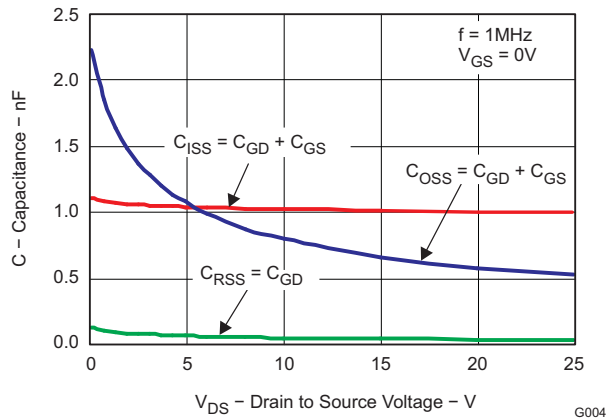


Figure 6. Capacitance

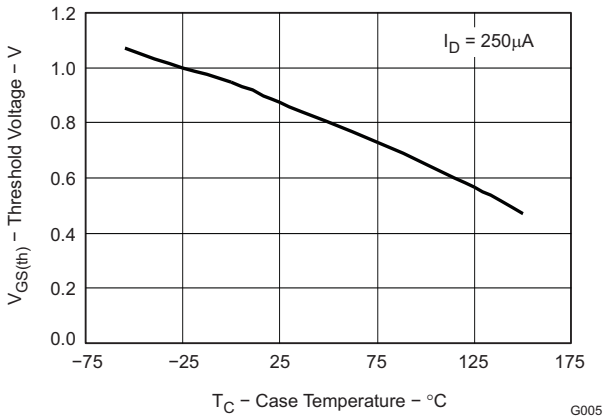


Figure 7. Threshold Voltage vs. Temperature

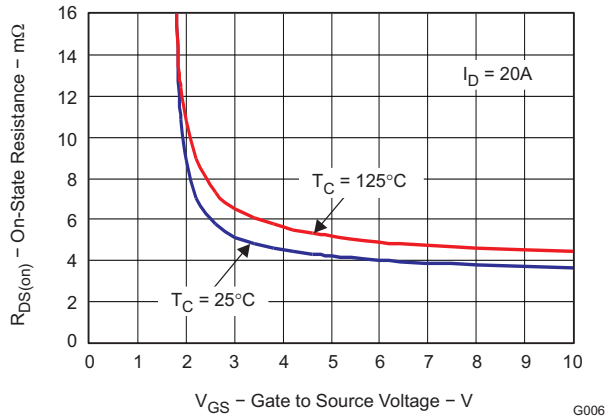


Figure 8. On Resistance vs. Gate Voltage

TYPICAL MOSFET CHARACTERISTICS (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

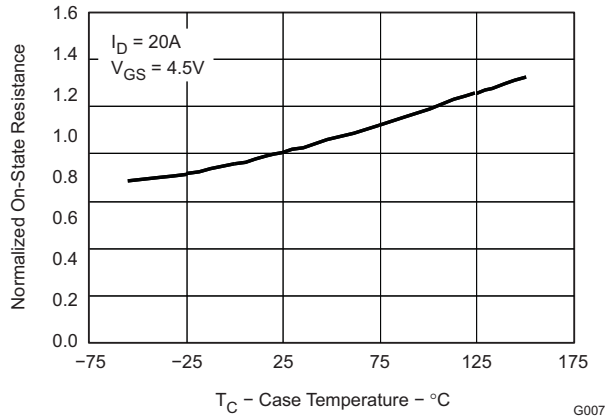


Figure 9. Normalized On Resistance vs. Temperature

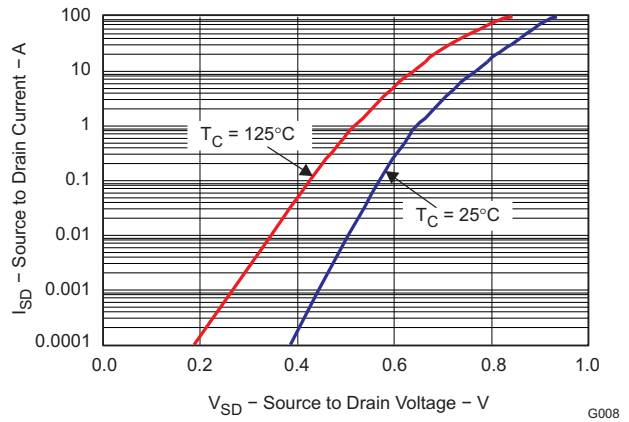


Figure 10. Typical Diode Forward Voltage

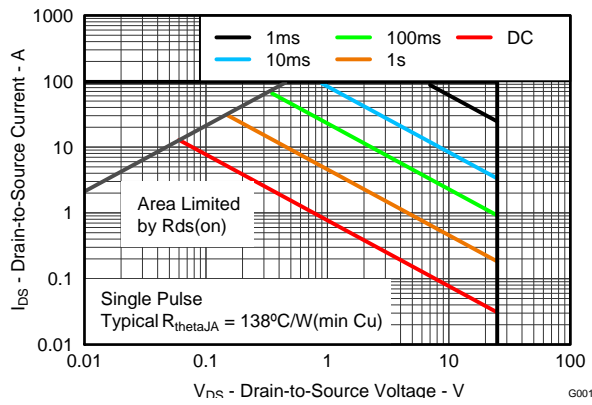


Figure 11. Maximum Safe Operating Area

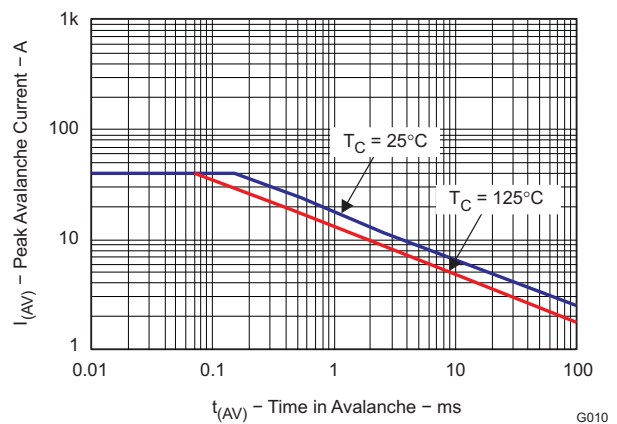


Figure 12. Single Pulse Unclamped Inductive Switching

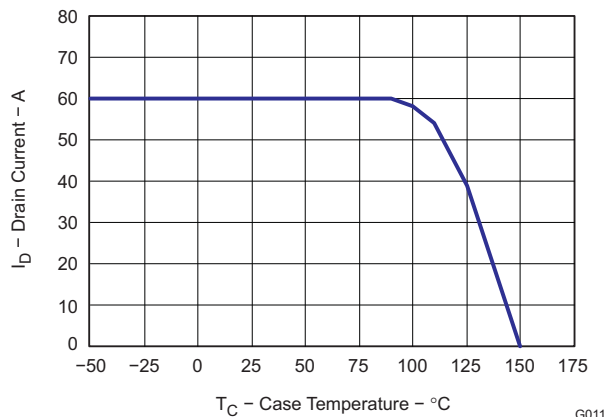
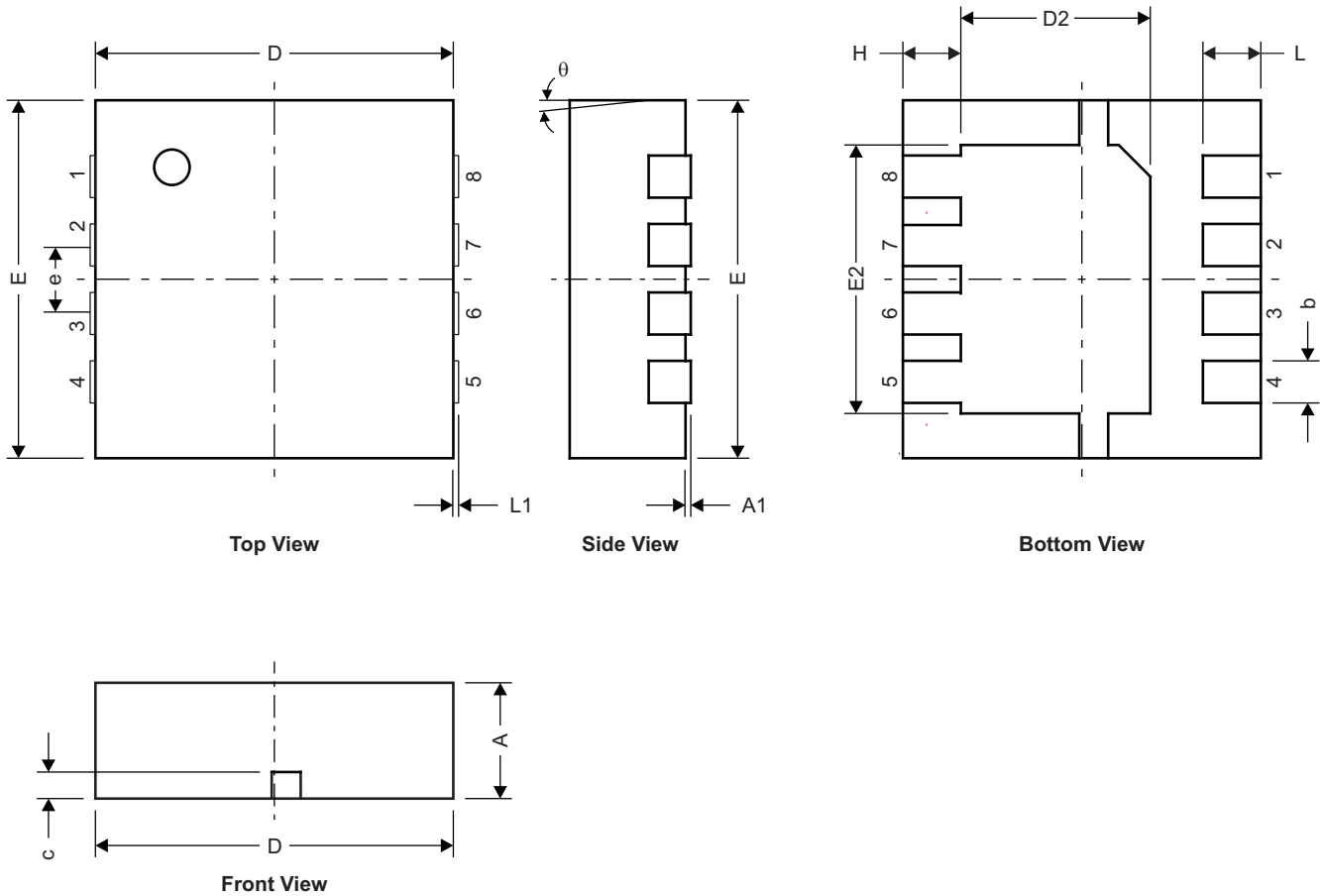


Figure 13. Maximum Drain Current vs. Temperature

MECHANICAL DATA

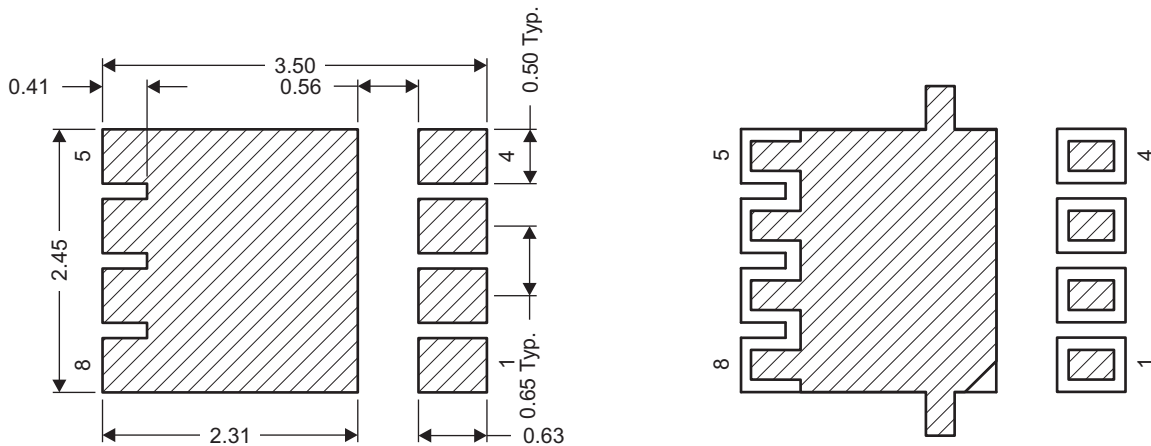
Q3 Package Dimensions



M0142-01

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.950	1.000	1.100	0.037	0.039	0.043
A1	0.000	0.000	0.050	0.000	0.000	0.002
b	0.280	0.340	0.400	0.011	0.013	0.016
c	0.150	0.200	0.250	0.006	0.008	0.010
D	3.200	3.300	3.400	0.126	0.130	0.134
D1	-	-	-	-	-	-
D2	1.650	1.750	1.800	0.065	0.069	0.071
E	3.200	3.300	3.400	0.126	0.130	0.134
E1	-	-	-	-	-	-
E2	2.350	2.450	2.550	0.093	0.096	0.100
e	0.650 TYP			0.026		
H	0.35	0.450	0.550	0.014	0.018	0.022
L	0.35	0.450	0.550	0.014	0.018	0.022
L1	-	-	-	-	-	-
θ	-	-	-	-	-	-

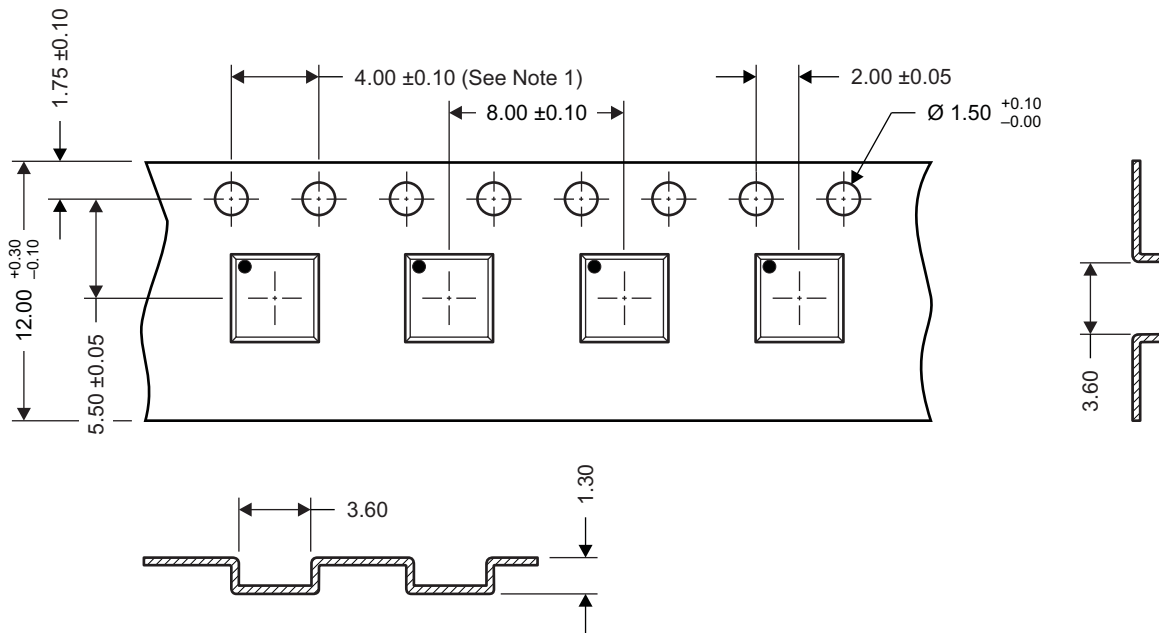
Recommended PCB Pattern



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For recommended circuit layout for PCB designs, see application note [SLPA005 – Reducing Ringing Through PCB Layout Techniques](#).

Q3 Tape and Reel Information



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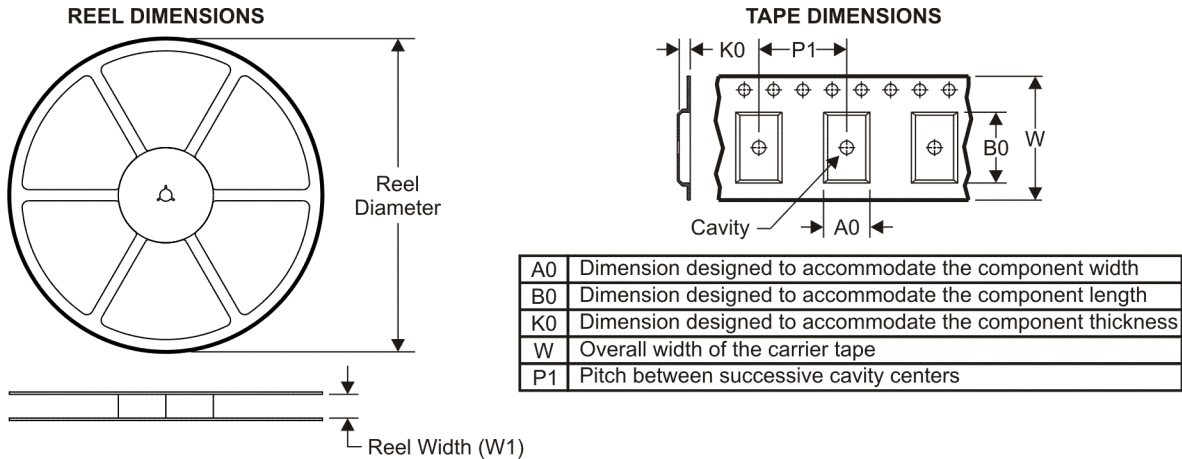
Notes:

1. 10 sprocket hole pitch cumulative tolerance ± 0.2
2. Camber not to exceed 1mm IN 100mm, noncumulative over 250mm
3. Material: black static dissipative polystyrene
4. All dimensions are in mm (unless otherwise specified)
5. Thickness: 0.30 ± 0.05 mm
6. MSL1 260°C (IR and Convection) PbF Reflow Compatible

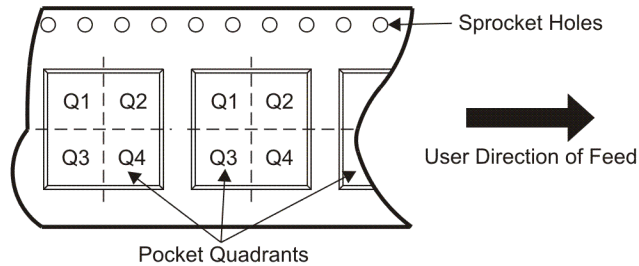
REVISION HISTORY

Changes from Original (December 2009) to Revision A	Page
• Changed Q_g in the PRODUCT SUMMARY table from: 6.8 To 6.5 nC	1
Changes from Revision A (January 2010) to Revision B	Page
• Changed Figure 3 , reversed the order of the V_{GS} labels	4
Changes from Revision B (September 2010) to Revision C	Page
• the Package Marking Information section	7
Changes from Revision C (September 2010) to Revision D	Page
• Replaced the THERMAL CHARACTERISTICS table with the new Thermal Information Table	2
• Replaced Figure 11 - Maximum Safe Operating Area	5

TAPE AND REEL INFORMATION



QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD16340Q3	SON	DQG	8	2500	330.0	12.8	3.6	3.6	1.2	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD16340Q3	SON	DQG	8	2500	335.0	335.0	32.0

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